

## DATA SHEET

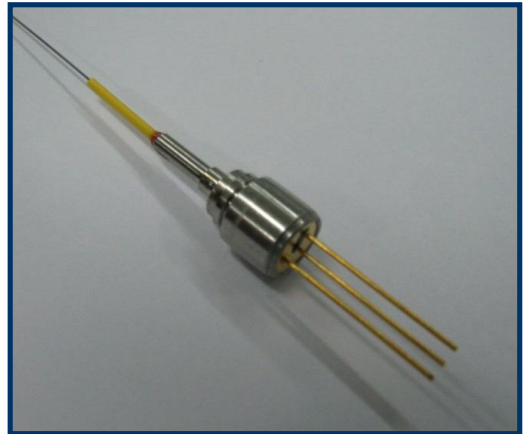


# Low Noise InGaAs PIN PD Module for Optical Power Monitor

XL P/N **XPD0250C-002-  
MNCN**

## FEATURES

- High responsivity
- Low dark current under 0.5 nA
- Low back reflection
- Bandwidth up to 2.6 GHz
- Large dynamic range & High saturation power
- Low cost coaxial type package



## APPLICATIONS

- Monitors for optical amplifiers
- Wavelength monitors for DWDM or CWDM

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25 °C)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Photodiode bias voltage	V <sub>PD</sub>	-	1.0	-	5.0	V
Dark current	I <sub>D</sub>	V <sub>PD</sub> = 2.5 V, 25 °C V <sub>PD</sub> = 2.5 V, 75 °C		0.05	0.5 2	nA
3dB bandwidth (small signal)	F <sub>3dB</sub>	Pin=-10dBm	2.5			GHz
Total capacitance	C <sub>PD</sub>	f = 1MHz, V <sub>PD</sub> = 5.0 V case not grounded			0.7	pF
Responsivity	R	λ = 1550nm λ = 980nm	0.85 0.53			A/W

## OPTICAL CHARACTERISTICS (T<sub>C</sub> = 25 °C)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Optical wavelength Range	λ	-	1100	-	1600	nm
Linear optical power range	P <sub>in</sub>	λ = 1550nm, ΔR<5% , V <sub>PD</sub> = 2.5 V	-40		5	dBm
Polarization dependence on Responsivity	PDR	λ = 1550nm, Pin=-3dBm V <sub>PD</sub> = 2.5 V			0.1	dB
Optical return loss	RL	λ = 1550nm	30			dB

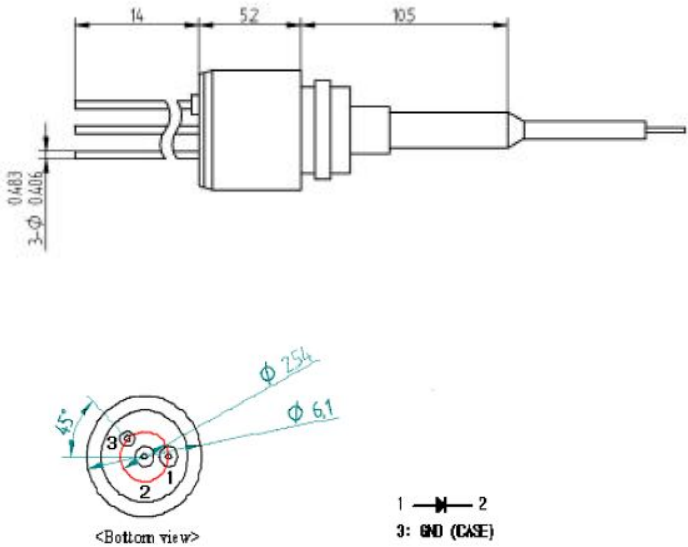
# Low Noise InGaAs PIN PD Module for Optical Power Monitor

**XPD0250C-002-MNCN**

**ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C)**

Parameter	Symbol	Rating	Unit
Photodiode bias voltage	V <sub>PD</sub>	20	V
Breakdown voltage (I <sub>R</sub> = 100 μA)	V <sub>BR</sub>	30	V
Forward current (under forward bias)	I <sub>F</sub>	2	mA
Reverse current (under reverse bias)	I <sub>R</sub>	10	mA
Operating case temperature range	T <sub>C</sub>	-20 to +75	°C
Storage temperature range	T <sub>STG</sub>	-40 to +85	°C
Soldering temperature (within 10 sec.)	T <sub>sold</sub>	260	°C

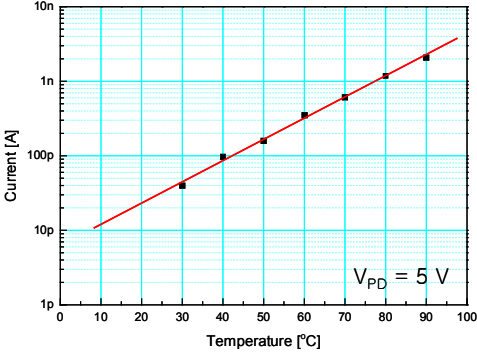
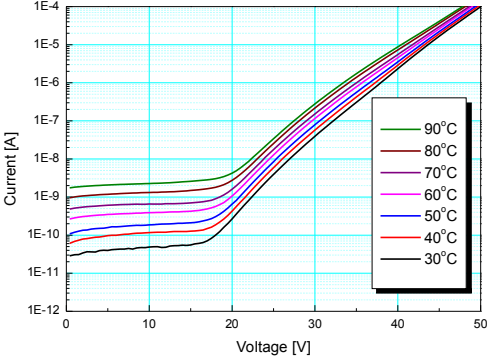
**MECHANICAL DIMENSIONS (unit : mm)**



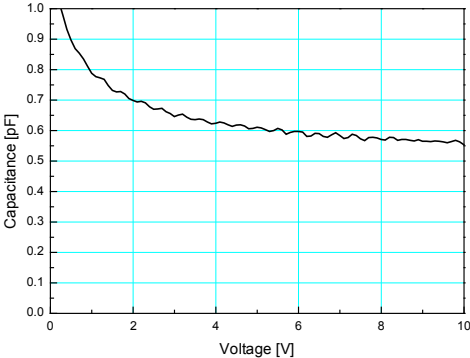
# Low Noise InGaAs PIN PD Module for Optical Power Monitor

XPD0250C-002-MNCN

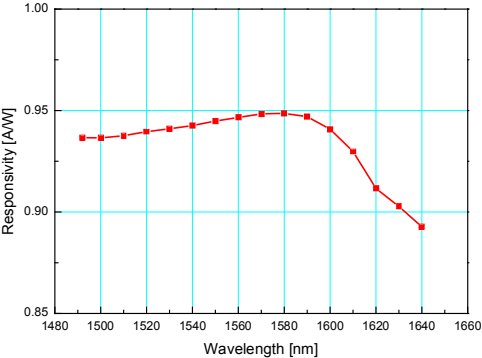
## DARK CURRENT DEPENDENCE ON TEMPERATURE



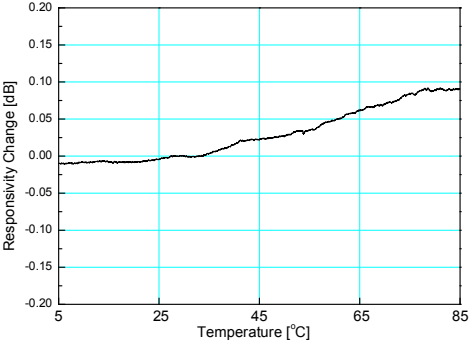
## C-V CHARACTERISTICS



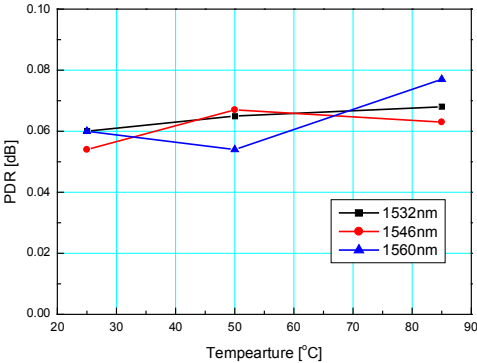
## SPECTRAL RESPONSE



## RESPONSIVITY VS. TEMPERATURE



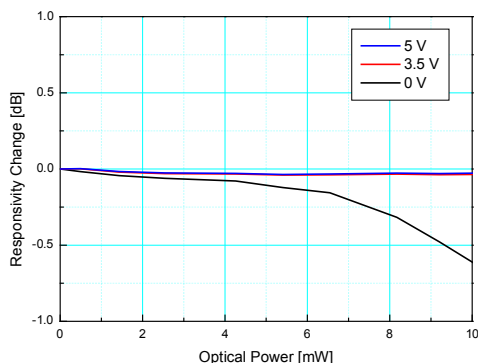
## PDR VS. WAVELENGTH, TEMPERATURE



# Low Noise InGaAs PIN PD Module for Optical Power Monitor

**XPD0250C-002-MNCN**

## OPTICAL POWER LINEARITY



## PRECAUTIONS FOR USE

ESD protection is imperative. Use of ground straps, anti static mats, and other standard ESD protective equipment is recommended when handling or testing an InGaAs PIN/APD or any other junction photodiode.

Soldering temperature of the leads should not exceed 260°C for more than 10 seconds.

Fiber pigtailed should be handled with less than 10 N pull and with a bending radius greater than 1 inch.

## ORDERING INFORMATION

Model name				Option		
PD type	Bandwidth (Hz)	Package Type	Code	Fiber	Connector type	Flange
XPD: PIN PD	0250: 2.5G	C:Coaxial type	002	M : MM-S105/125-15A Specialty Multimode Fiber 2 meter	NC: No connector	N: No flange

ex) XPD0250C-002-MNCN

Low noise TO coaxial type InGaAs PIN PD module for power monitoring application with MM-S105/125-15A Specialty Multimode Fiber, no connector, no flange

## REVISION HISTORY

Date	Revision	Description
January 2003	001	Initial release
June 2004	002	Dark current, capacitance changed
January 2007	003	Update
March 2014	A	Add Nufern PN, Fiber PN and change revision no.

URL: [www.XL-photonics.com](http://www.XL-photonics.com) E-mail: [sales@XL-photonics.com](mailto:sales@XL-photonics.com)

59-8 Jang-Dong, Yusong-Gu, Daejeon 305-343, South Korea

TEL: +82-42-3600-100 FAX: +82-42-3600-101

© 2007 XL Photonics, Inc. All rights reserved. (January 2007)